

IECQ-CECC QC 88000-C002

COMPONENT ISSUE 1

SPECIFICATION March 2007

# Component Specification For Ceramic Hermetically Sealed High Speed Optocouplers





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#### **FOREWORD**

The IECQ Quality Assessment System for Electronic Components (IECQ) is composed of those member countries of the International Electrotechnical Commission (IEC) who wish to take part in a harmonized system for electronic components of assessed quality. IECQ is also known in some European member countries as IECQ-CECC.

The object of the System is to facilitate international trade by the harmonization of the specifications and quality assessment procedures for electronic components, and by the grant of an internationally recognised Mark, or Certificate of Conformity. The components produced or services provided under the system are thereby acceptable in all member countries without further testing.

This Component Specification is based upon the requirements of IEC Publication QC 001002-2, and has been prepared by:

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and published under the authority of:

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#### AMENDMENT RECORD

No previous issue.

#### **REQUIREMENTS**

The requirements for IECQ-CECC Component Specifications as detailed in QC 001002-2 Amendment 1 clause 5.4 are satisfied by the following data sheet.

It should note that IECQ-CECC are not responsible for manufacturers declarations made in data sheets which fall outside the limits of approved detailed in IECQ-CECC certificates.

This Component Specification is intended for use with applicable IECQ-CECC Assessment Specifications. Eg: QC 88000-A0001

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# **Ceramic Hermetically Sealed High Speed Optocouplers**

■ 4N55

■ CD850

■ CH380

■ CS800/801

■ CSM168-2

■ CSM168-4

■ CSM1801

■ CSM1800

**■ MC800** 

# **Features**

- Release to IECQ-CECC
- Hermetically Sealed
- High Density Packaging
- 1500V DC withstand Test Voltage
- Low Input Requirements
- High Current Transfer Ratio

# **Applications**

- Military, high reliability system
- Medical instruments
- Mos, Cmos Applications
- Logic Interfacing
- Data Transmission
- Power Supply

# **Description**

These devices are single, dual and quad, hermetically sealed optocouplers. Each channel is composed of a Gallium Arsenide infra-red emitting diode and a silicon phototransistor. Package styles for these devices include 6 pin, 8 pin, 16 pin flat pack, and hybrid 4 pin, with surface mount, butt cut and gull wing options available.

The same electrical die, assembly processes and materials are used for each channel of each device shown below. Therefore absolute maximum ratings, recommended operating conditions, electrical specifications and performance characteristics are identical for all units. Any exceptions, due to packaging variations and limitations, are as noted.

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# **Selection Guide Package Styles and Configuration Options**

Package	16 pin DIP	8 pin DIP	6 pin Hybrid	16 pin Flat Pack	6 Pad LCC	6pin metal Can TO-5
Lead Style						
Channels	2	1/2	1	4	1	1
Common Channel Wiring						

**Isocom Part Numbers and Options** 

	4N55	CS800/801				MC800
Commercial		CD850	CH380	CSM168-2/4	CSM1800/01	
	4N55/L2	CS800/801/L2		CSM168-		MC800/L2
Defense Level		CD850/L2	CH380/L2	2/4/L2	CSM1800/01	
	4N55/L2S	CS800/801/L2S		CSM168-		MC800/L2S
Space Level		CD850/L2S	CH380/L2S	2/4/L2S	CSM1800/01	
Standard Gold Plate Finish	Gold Plate	Gold Plate	Gold Plate	Gold Plate	Gold Plate	Gold Plate
Solder Dipped	Option 20	Option 20	Option 20			
Butt Cut/Gold Plate	Option 10	Option 10	Option 10			
Gull Wing/Soldered	Option 30	Option 30	Option 30			
Crew Cut/Gold Plate	Option 60	Option 60	Option 60			

# **Functional Diagrams**

CH380	CS800/801	CD850	4N55	CSM168-4 CSM168-2	CSM1800/01
1 Channel	1 Channel	2 Channel	2 Channel	2-4 Channel	1 Channel
5 4 3	8 7 6 5 	8 7 6 5 (大) (大) (大) (大) (大) (大) (大) (大)	16 15 14 13 12 11 10 9 	16 15 14 13 12 11 10 9	5 1 2
MC800			_		_

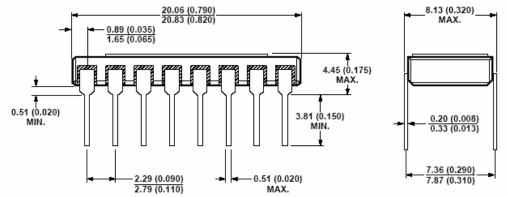
1 Channel

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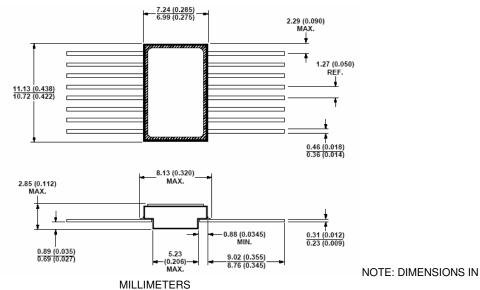


# **Outline Drawings**

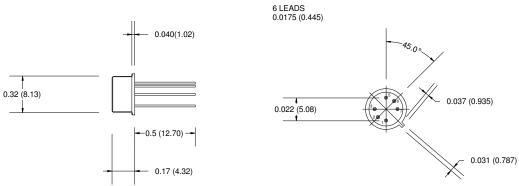
### 16 pin DIP, 4 Channel



#### 16 pin Flat Pack, 4 Channel



#### 6 pin TO-5, 1 Channel



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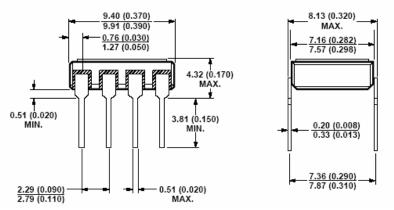
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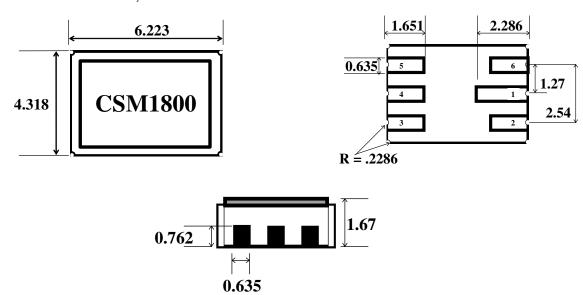
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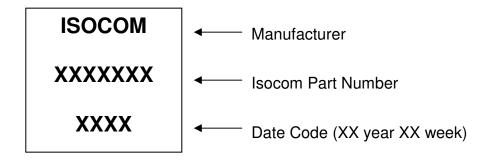
#### 8 pin DIP 1 and 2 Channel



#### 6 Terminal LCC Surface Mount, 1 Channel



# **Device Marking**



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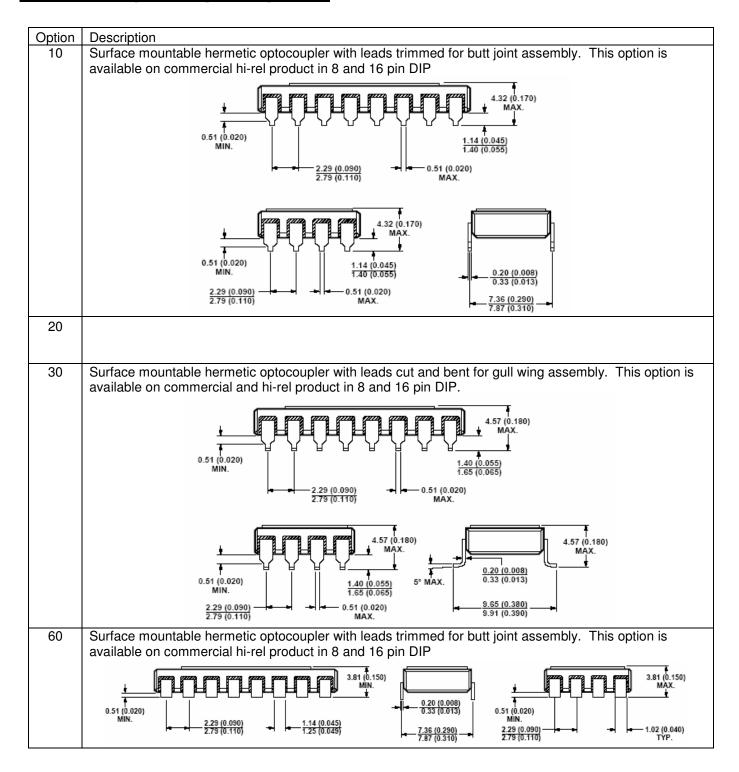
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# **Hermetic Optocoupler Options**



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# **Absolute Maximum Ratings**

Storage Temperature	-65°C to +150°C
Operating Temperature	-55°C to +125°C

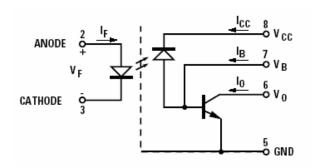
## **Input Diode**

Peak Forward Current	40mA	≤ 1 mS duration
Average Forward Current	20mA	
Reverse Voltage	5V	
Power Dissipation	36mW	Derate linearly above 100°C at 1.4W/°C for CH380 and
		CS800/801

**Output Detector** 

Supply Voltage	-0.5 to 20V	$V_{CC}$
Average Current	8mA	$I_0$
Peak Current	16mA	$I_0$
Voltage	-0.5 to 20V	Vo
Power Dissipation	40mW	For CH380 and CS800/801
	50mW	Derate linearly above 100°C at 1.4W/°C for CD850, CSM6530 and 4N55
Emitter-Base Reverse Voltage	3V	$\mathrm{BV}_{\mathrm{EBO}}$
Base Current	5mA	$I_{\mathrm{B}}$

# **Single Channel Schematic**



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Electrical Characteristics  $T_{A=}$  -55 °C to +125 °C U.O.S.

All typical values at  $V_{CC}$  = 5V,  $T_{A}$  = 25 °C (each channel where appropriate).

Parameter	Symbol	Test Conditions	Device	Min	Туре	Max	Units
Current Transfer Ratio	h <sub>f(CTR)</sub>	$V_{CC} = 4.5V, V_{O} = 0.4V, I_{F} = 16mA,$		9	20	-	%
(See notes 1 & 2)			CS801	15	-		
		$V_{CC} = 4.5V, V_{O} = 0.5V, I_{F} = 16mA$	CD850	9	17	-	
Logic Low Output Voltage	V <sub>OL</sub>	$V_{CC} = 4.5V, I_F = 16mA$ $I_O = 1.44mA$		-	0.3	0.4	٧
			CD850	-	0.3	0.5	1
Logic High Output Current (See note 1)	I <sub>ОН</sub>	$I_{F1} = 0$ , $I_{F2} = 20mA$ $V_O = V_{CC} = 18V$		-	30	250	μΑ
		$I_{F1} = F_2 = 20 \text{mA}, V_0 = V_{CC} = 15$	CD850 CSM1800				
Logic Low Supply Current (See note 1)	I <sub>CCL</sub>	$V_{CC} = 18V$ , $I_{F1} = I_{F2} = 20Ma$		-	30	200	μΑ
,		V <sub>CC</sub> = 18V, I <sub>F1</sub> = 20Ma	CS800/1				
		V <sub>CC</sub> = 15V I <sub>F1</sub> = 16Ma I <sub>F2</sub> =0	CH380 CSM1800				
		$V_{CC} = 16V_{F1} = I_{F2} = 16mA$	CD850			400	
Logic High Supply Current (See note 1)	I <sub>CCH</sub>	$Vcc = 18V$ , $I_F = 0mA$ , $IF$ (other channel) = $20mA$		-	0.4	10	μА
Input Forward Voltage (See note 1)	V <sub>F</sub>	I <sub>F</sub> = 20mA		-	1.45	1.9	V
Input Reverse Breakdown (See note 1)	$V_{BR}$	$I_R = 10\mu A$		3	-	-	V
Input-Output Insulation Leakage Current	I <sub>IO</sub>	RH = 45%, T <sub>A</sub> = 25 °C, t = 5S V <sub>IO</sub> = 1500VDC		-	-	1.0	μА
(See notes 3 & 9)		RH = 45%, T <sub>A</sub> = 25 °C, t = 5S V <sub>IO</sub> = 500VDC	CH380				
Propagation Delay Time to Logic Low at Output (See note 1)	t <sub>PHL</sub>	$R_L = 8.2K\Omega$ , $I_F = 16mA$ , $V_{CC} = 5V$ $C_L = 50pF$		-	0.4	2.0	μS
(,		$R_L = 1.9K, I_F = 16mA, V_{CC} = 5V$	CD850 CSM1800			2.0	
Propagation Delay Time to Logic High at Output (See note 1)	t <sub>PLH</sub>	$R_L = 8.2K\Omega$ , $I_F = 16mA$ , $V_{CC} = 5V$ $C_L = 50pF$		-	2.0	6.0	μS
(See note 1)		$R_L = 1.9K$ , $I_F = 16mA$ , $V_{CC} = 5V$	CD850 CSM1800			6.0	-

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# **Typical Characteristics**

T<sub>A</sub> = 25℃

Parameter	Symbol	Test Conditions	Notes	Min	Type	Max	Units
Temperature Coefficient of Forward Voltage	$\frac{\Delta_{\text{VF}}}{\Delta_{-}}$	$I_F = 20 \text{mA}$	1	-	-1.9	-	mV/℃
Input Capacitance	$\Delta_{TA}$ $C_{IN}$	$f = 1 \text{mhz}, V_F = 0$	1	<del> </del>	125	_	pF
Resistance (Input-Output)	R <sub>I-O</sub>	$V_{1-0} = 500 \text{Vdc}$	1	-	10 <sup>12</sup>	_	Ω
Capacitance (Input- Output)	C <sub>I-O</sub>	f = 1MHz	1 & 4	-	1.0	-	pF
Input-Input Insulation Leakage Current	I <sub>I-I</sub>	45% Relative Humidity VH = 500Vdc, t = 5S	5	-	1	-	рА
Capacitance (Input-Input)	C <sub>I-I</sub>	f = 1MHz	5	-	0.6	-	pF
Transistor DC Current Gain	hFE	$V_O = 5V$ , $I_O = 3mA$	1	-	130	-	-
Small Signal Current Transfer Ratio	<u>Δl<sub>O</sub></u> Δl <sub>F</sub>	$V_{CC} = 5V$ , $V_O = 2V$	1	-	20	-	%
Common Mode Transient Immunity at Logic Low Level Output	CM <sub>L</sub>	$I_F = 16\text{mA}, R_L = 8.2\text{K}\Omega$ $V_{CM} = 10V_{P-P}$ $V_O \text{ (max)} = 0.8\text{V}$	1 & 7	-	-1000	-	V/µS
Common Mode Transient Immunity at Logic High Level Output	CM <sub>H</sub>	$I_F = 0mA, R_L = 8.2K\Omega$ $V_{CM} = 10V_{P-P}$ $V_O(max) = 2.0V$	1 & 6	-	1000	-	V/µS
Bandwidth	BW	$RL = 100\Omega$	8	-	2	-	MHz

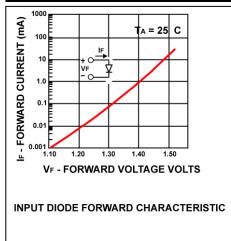
#### Notes (Apply typically to 16 pin package)

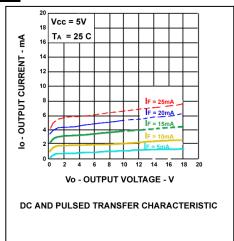
- 1. Each channel, where appropriate.
- 2. Current Transfer ratio is defined as the ratio of output collector current, IO, to the forward LED input current, I<sub>F</sub>, times 100%. CTR is known to degrade slightly over the unit's lifetime as a function of input current, temperature, signal duty cycle and system on time. It is recommended that designers allow at least 20-25% guard band for CTR degradation.
- 3. Measured between pins 1 through 8 shorted together, and pins 9 through 16 shorted together.
- 4. Measured between each input pair shorted together, and the output pins for that channel shorted together.
- 5. Measured between pins 3 and 4 shorted together, and pins 7 and 8 shorted together.
- 6.  $CM_H$  is the steepest slope (dV/dt) on the leading edge of the common mode pulse,  $V_{CM}$ , for which the output will remain in the logic high state (i.e.,  $V_O > 2.0V$ ).
- 7.  $CM_L$  is the steepest slope (dV/dt) on the trailing edge of the common mode pulse,  $V_{CM}$ , for which the output will remain in the logic low state (i.e., VO < 0.8V).
- 8. Bandwidth is the frequency at which the AC output voltage is 3dB below the low frequency asymptote.
- 9. This is a momentary withstand test, not an operating condition.

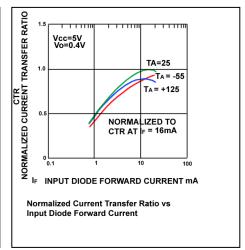
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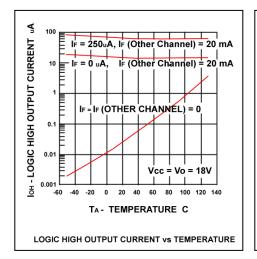


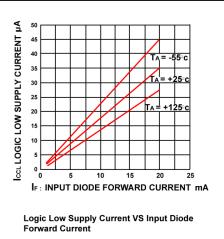
# **Electrical Characteristics**

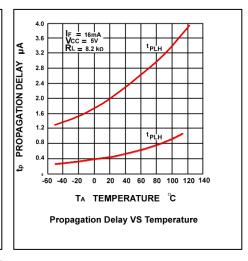


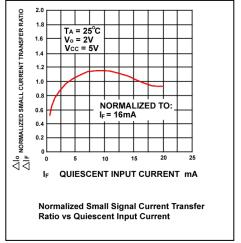






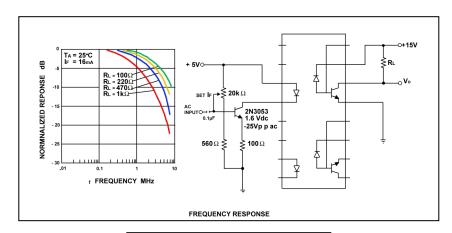


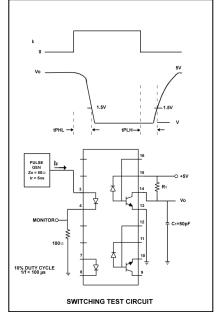


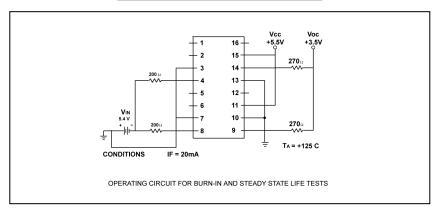


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